Tian-Ling Ren

List of Publications by Year in Descending Order

242 papers	7,885 citations	43 h-index	83 g-index
300 ext. papers	9,854 ext. citations	6.9 avg, IF	6.1 L-index

#	Paper	IF	Citations
242	Industrial-scale production of high-quality graphene sheets by millstone grinders. *Journal Physics D: Applied Physics*, **2022**, 55, 164002	3	1
241	High-Throughput DNA Tensioner Platform for Interrogating Mechanical Heterogeneity of Single Living Cells.. *Small*, **2022**, 18, e2106196	11	6
240	Impact of Molybdenum Oxide Electrode on the Ferroelectricity of Doped-Hafnia Oxide Capacitors. *IEEE Transactions on Electron Devices*, **2022**, 1-5	2.9	1
239	Mini-review: Novel Graphene-based Acoustic Devices. *Sensors and Actuators Reports*, **2022**, 100086	4.7	1
238	A Better Zn-Ion Storage Device: Recent Progress for Zn-Ion Hybrid Supercapacitors.. *Nano-Micro Letters*, **2022**, 14, 64	19.5	5
237	Vertical MoS transistors with sub-1-nm gate lengths.. *Nature*, **2022**, 603, 259-264	50.4	18
236	Electrooculography and Tactile Perception Collaborative Interface for 3D Human-Machine Interaction.. *ACS Nano*, **2022**,	16.7	6
235	Two-stage amplification of an ultrasensitive MXene-based intelligent artificial eardrum.. *Science Advances*, **2022**, 8, eabn2156	14.3	11
234	Nomex paper-based double-sided laser-induced graphene for multifunctional human-machine interfaces. *Carbon*, **2022**, 193, 68-76	10.4	2
233	Ultrathin encapsulated rGO strain sensor for gesture recognition. *Microelectronic Engineering*, **2022**, 259, 111779	2.5	2
232	Biocompatible Sensors Are Revolutionizing Healthcare Technologies **2022**, 227-249		
231	Ultra-low Voltage Schmitt Triggers Implemented by HfO2-based Ferroelectric Field-Effect Transistors. *IEEE Electron Device Letters*, **2022**, 1-1	4.4	1
230	Graphene-Based Flexible Electrode for Electrocardiogram Signal Monitoring. *Applied Sciences (Switzerland)*, **2022**, 12, 4526	2.6	1
229	Electrospun Nanofibers for Integrated Sensing, Storage, and Computing Applications. *Applied Sciences (Switzerland)*, **2022**, 12, 4370	2.6	2
228	The trend of 2D transistors toward integrated circuits: Scaling down and new mechanisms.. *Advanced Materials*, **2022**, e2201916	24	4
227	Intelligent and Multifunctional Graphene Nanomesh Electronic Skin with High Comfort. *Small*, **2021**, e2104810	11	14
226	Interfacial Regulation of Dielectric Properties in Ferroelectric Hf0.5Zr0.5O2 Thin Films. *IEEE Journal of the Electron Devices Society*, **2021**, 9, 1093-1097	2.3	

225	Ferroelectric structural transition in hafnium oxide induced by charged oxygen vacancies. *Physical Review B*, **2021**, 104,	3.3	5
224	Ultrasensitive Detection of COVID-19 Causative Virus (SARS-CoV-2) Spike Protein Using Laser Induced Graphene Field-Effect Transistor. *Molecules*, **2021**, 26,	4.8	3
223	Highly Stretchable and Conformal Electromagnetic Interference Shielding Armor with Strain Sensing Ability. *Chemical Engineering Journal*, **2021**, 133908	14.7	3
222	A 10□hm Short Channel MoS2 Transistor without the Resolution Requirement of Photolithography. *Advanced Electronic Materials*, **2021**, 7, 2100543	6.4	3
221	Graphene-Based Multifunctional Textile for Sensing and Actuating. *ACS Nano*, **2021**,	16.7	11
220	Hippocampal Neurons□Alignment on Quartz Grooves and Parylene Cues on Quartz Substrate. *Applied Sciences (Switzerland)*, **2021**, 11, 275	2.6	3
219	Filling the gap: thermal properties and device applications of graphene. *Science China Information Sciences*, **2021**, 64, 1	3.4	3
218	Multifunctional Graphene Microstructures Inspired by Honeycomb for Ultrahigh Performance Electromagnetic Interference Shielding and Wearable Applications. *ACS Nano*, **2021**, 15, 8907-8918	16.7	36
217	The manufacture and characterization of a novel ultrasonic transducer for medical imaging **2021**,		1
216	Compact, Flexible, and Transparent Antennas Based on Embedded Metallic Mesh for Wearable Devices in 5G Wireless Network. *IEEE Transactions on Antennas and Propagation*, **2021**, 69, 1864-1873	4.9	13
215	Gate-Tunable Negative Differential Resistance Behaviors in a hBN-Encapsulated BP-MoS Heterojunction. *ACS Applied Materials & Interfaces*, **2021**, 13, 26161-26169	9.5	7
214	The Origin of CBRAM With High Linearity, On/Off Ratio, and State Number for Neuromorphic Computing. *IEEE Transactions on Electron Devices*, **2021**, 68, 2568-2571	2.9	5
213	Roll-to-roll graphene films for non-disposable electrocardiogram electrodes. *Journal Physics D: Applied Physics*, **2021**, 54, 364003	3	3
212	Observation of negative capacitance in antiferroelectric PbZrO Films. *Nature Communications*, **2021** , 12, 4215	17.4	5
211	Stability diagrams of two optically mutual-injected quantum cascade lasers. *AIP Advances*, **2021**, 11, 015320	1.5	
210	A Shoe-Integrated Sensor System for Long-Term Center of Pressure Evaluation. *IEEE Sensors Journal*, **2021**, 1-1	4	1
209	Enhancing the Ultraviolet Photocurrent and Response Speed of Zinc Oxide Nanoflowers using Surface Plasmons of Gold Nanoparticles and a Graphene Membrane. *Physica Status Solidi - Rapid Research Letters*, **2021**, 15, 2000512	2.5	1
208	High-performance single crystal CH3NH3PbI3 perovskite x-ray detector. *Applied Physics Letters*, **2021**, 118, 063506	3.4	8

207	Ultrahigh Step-Up Coupled-Inductor DC-DC Converter With Soft-Switching for Driving Piezoelectric Actuators. *IEEE Transactions on Circuits and Systems II: Express Briefs*, **2021**, 68, 2902-2906	3.5	2
206	Reconfigurable Logic-Memory Hybrid Device Based on Ferroelectric Hf0.5Zr0.5O2. *IEEE Electron Device Letters*, **2021**, 42, 1164-1167	4.4	8
205	Self-Powered Multicolor Broadband Photodetector Based on GaSe/WSe2/WSe2/BP Van Der Waals Heterostructure. *IEEE Transactions on Electron Devices*, **2021**, 68, 3881-3886	2.9	0
204	Black phosphorus junctions and their electrical and optoelectronic applications. *Journal of Semiconductors*, **2021**, 42, 081001	2.3	5
203	An Integrated Luminescent Information Encryption–Decryption and Anticounterfeiting Chip Based on Laser Induced Graphene. *Advanced Functional Materials*, **2021**, 31, 2103255	15.6	5
202	Reconfigurable MoTe2 Field-Effect Transistors and its Application in Compact CMOS Circuits. *IEEE Transactions on Electron Devices*, **2021**, 68, 4748-4753	2.9	2
201	Fabricating In-Plane MoTe2 p-n Homojunction Photodetector Using Laser-Induced p-Type Doping. *IEEE Transactions on Electron Devices*, **2021**, 68, 4485-4490	2.9	1
200	Ambipolar transport compact models for two-dimensional materials based field-effect transistors. *Tsinghua Science and Technology*, **2021**, 26, 574-591	3.4	1
199	Transistor Subthreshold Swing Lowered by 2-D Heterostructures. *IEEE Transactions on Electron Devices*, **2021**, 68, 411-414	2.9	1
198	A review on low-dimensional novel optoelectronic devices based on carbon nanotubes. *AIP Advances*, **2021**, 11, 110701	1.5	1
197	A Miniaturized Integrated SAW Sensing System for Relative Humidity Based on Graphene Oxide Film. *IEEE Sensors Journal*, **2020**, 20, 9733-9739	4	6
196	Fabrication and Characterization of Ferroelectric HfZrO-based Synaptic Transistors with Multi-state Plasticity **2020**,		3
195	High Performance and Wireless Graphene Earphone towards Practical Applications **2020**,		1
194	Encapsulated X-Ray Detector Enabled by All-Inorganic Lead-Free Perovskite Film With High Sensitivity and Low Detection Limit. *IEEE Transactions on Electron Devices*, **2020**, 67, 3191-3198	2.9	15
193	Fabrication and Characterization of a Novel Si Line Tunneling TFET With High Drive Current. *IEEE Journal of the Electron Devices Society*, **2020**, 8, 336-340	2.3	15
192	Graphene-Based Thermoacoustic Sound Source. *ACS Nano*, **2020**, 14, 3779-3804	16.7	12
191	Lower Power, Better Uniformity, and Stability CBRAM Enabled by Graphene Nanohole Interface Engineering. *IEEE Transactions on Electron Devices*, **2020**, 67, 984-988	2.9	4
190	Thermal Energy Conversion: Graphene-Based Devices for Thermal Energy Conversion and Utilization (Adv. Funct. Mater. 8/2020). *Advanced Functional Materials*, **2020**, 30, 2070052	15.6	

189	Utilization of Synergistic Effect of Dimension-Differentiated Hierarchical Nanomaterials for Transparent and Flexible Wireless Communicational Elements. *Advanced Materials Technologies*, **2020**, 5, 1901057	6.8	2
188	Ultrafast Photodetector by Integrating Perovskite Directly on Silicon Wafer. *ACS Nano*, **2020**, 14, 2860-2868	16.7	52
187	. *IEEE Transactions on Electron Devices*, **2020**, 67, 2153-2156	2.9	11
186	Highly Transparent and Sensitive Graphene Sensors for Continuous and Non-invasive Intraocular Pressure Monitoring. *ACS Applied Materials & Interfaces*, **2020**, 12, 18375-18384	9.5	25
185	High-Quality Single Crystal Perovskite for Highly Sensitive X-Ray Detector. *IEEE Electron Device Letters*, **2020**, 41, 256-259	4.4	19
184	Fabricating Molybdenum Disulfide Memristors. *ACS Applied Electronic Materials*, **2020**, 2, 346-370	4	10
183	Substrate-Free Multilayer Graphene Electronic Skin for Intelligent Diagnosis. *ACS Applied Materials & Interfaces*, **2020**, 12, 49945-49956	9.5	21
182	Triode-Mimicking Graphene Pressure Sensor with Positive Resistance Variation for Physiology and Motion Monitoring. *ACS Nano*, **2020**, 14, 10104-10114	16.7	79
181	Flexible Quasi-van der Waals Ferroelectric Hafnium-Based Oxide for Integrated High-Performance Nonvolatile Memory. *Advanced Science*, **2020**, 7, 2001266	13.6	15
180	Anomalous thermoacoustic effect in topological insulator for sound applications. *Applied Physics Letters*, **2020**, 117, 123502	3.4	1
179	Multifunctional and high-performance electronic skin based on silver nanowires bridging graphene. *Carbon*, **2020**, 156, 253-260	10.4	45
178	Graphene-Based Devices for Thermal Energy Conversion and Utilization. *Advanced Functional Materials*, **2020**, 30, 1903888	15.6	18
177	Wearable Electronics Based on 2D Materials for Human Physiological Information Detection. *Small*, **2020**, 16, e1901124	11	52
176	Graphene-based wearable sensors. *Nanoscale*, **2019**, 11, 18923-18945	7.7	50
175	Graphene based Wearable Sensors for Healthcare **2019**,		3
174	Flexible Two-Dimensional TiC MXene Films as Thermoacoustic Devices. *ACS Nano*, **2019**, 13, 12613-12620	16.7	28
173	Ultra-High Sensitive NO Gas Sensor Based on Tunable Polarity Transport in CVD-WS/IGZO p-N Heterojunction. *ACS Applied Materials & Interfaces*, **2019**, 11, 40850-40859	9.5	55
172	Two-Mode MoS Filament Transistor with Extremely Low Subthreshold Swing and Record High On/Off Ratio. *ACS Nano*, **2019**, 13, 2205-2212	16.7	17

171	Tunable electronic and optical properties of the WS/IGZO heterostructure via an external electric field and strain: a theoretical study. *Physical Chemistry Chemical Physics*, **2019**, 21, 14713-14721	3.6	3
170	Laser-reconfigured MoS/ZnO van der Waals synapse. *Nanoscale*, **2019**, 11, 11114-11120	7.7	10
169	Photoelectric Synaptic Plasticity Realized by 2D Perovskite. *Advanced Functional Materials*, **2019**, 29, 1902538	15.6	77
168	X-Ray Detector Based on All-Inorganic Lead-Free Cs2AgBiBr6 Perovskite Single Crystal. *IEEE Transactions on Electron Devices*, **2019**, 66, 2224-2229	2.9	38
167	Switching dynamics of ferroelectric HfO2-ZrO2 with various ZrO2 contents. *Applied Physics Letters*, **2019**, 114, 142902	3.4	24
166	Simultaneous synthesis and integration of two-dimensional electronic components. *Nature Electronics*, **2019**, 2, 164-170	28.4	54
165	Negative Capacitance Oxide Thin-Film Transistor With Sub-60 mV/Decade Subthreshold Swing. *IEEE Electron Device Letters*, **2019**, 40, 826-829	4.4	17
164	High sensitive surface-acoustic-wave optical sensor based on two-dimensional perovskite **2019**,		1
163	Stable InSe transistors with high-field effect mobility for reliable nerve signal sensing. *Npj 2D Materials and Applications*, **2019**, 3,	8.8	18
162	A Wearable Skinlike Ultra-Sensitive Artificial Graphene Throat. *ACS Nano*, **2019**, 13, 8639-8647	16.7	45
161	A novel thermal acoustic device based on vertical graphene film. *AIP Advances*, **2019**, 9, 075302	1.5	5
160	Light-Enhanced Ion Migration in Two-Dimensional Perovskite Single Crystals Revealed in Carbon Nanotubes/Two-Dimensional Perovskite Heterostructure and Its Photomemory Application. *ACS Central Science*, **2019**, 5, 1857-1865	16.8	23
159	Plasmon-Enhanced InGaZnO Ultraviolet Photodetectors Tuned by Ferroelectric HfZrO. *Advanced Electronic Materials*, **2019**, 5, 1900588	6.4	9
158	Graphene-Based Synaptic Devices for Neuromorphic Applications **2019**, 99-142		
157	Dual-Functional Nonvolatile and Volatile Memory in Resistively Switching Indium Tin Oxide/HfOx Devices. *Physica Status Solidi (A) Applications and Materials Science*, **2019**, 216, 1900555	1.6	1
156	Development of a portable setup using a miniaturized and high precision colorimeter for the estimation of phosphate in natural water. *Analytica Chimica Acta*, **2019**, 1058, 70-79	6.6	8
155	A contact lens promising for non-invasive continuous intraocular pressure monitoring.. *RSC Advances*, **2019**, 9, 5076-5082	3.7	20
154	An efficient flexible graphene-based light-emitting device. *Nanoscale Advances*, **2019**, 1, 4745-4754	5.1	14

153	Au Nanoparticles-Decorated Surface Plasmon Enhanced ZnO Nanorods Ultraviolet Photodetector on Flexible Transparent Mica Substrate. *IEEE Journal of the Electron Devices Society*, **2019**, 1-1	2.3	12
152	Negative Capacitance Black Phosphorus Transistors With Low SS. *IEEE Transactions on Electron Devices*, **2019**, 66, 1579-1583	2.9	10
151	Proton Conductor Gated Synaptic Transistor Based on Transparent IGZO for Realizing Electrical and UV Light Stimulus. *IEEE Journal of the Electron Devices Society*, **2019**, 7, 38-45	2.3	15
150	A Hybrid Phototransistor Neuromorphic Synapse. *IEEE Journal of the Electron Devices Society*, **2019**, 7, 13-17	2.3	8
149	Design and Characterization of High-Density Ultrasonic Transducer Array. *IEEE Sensors Journal*, **2018**, 18, 2285-2290	4	10
148	Graphene devices based on laser scribing technology. *Japanese Journal of Applied Physics*, **2018**, 57, 04FA01	1.4	7
147	Demonstration of □nGaZnO TFT Nonvolatile Memory Using TiAlO Charge Trapping Layer. *IEEE Nanotechnology Magazine*, **2018**, 17, 1089-1093	2.6	6
146	All-Inorganic Perovskite Nanowires-InGaZnO Heterojunction for High-Performance Ultraviolet-Visible Photodetectors. *ACS Applied Materials & Interfaces*, **2018**, 10, 7231-7238	9.5	40
145	. *IEEE Transactions on Nuclear Science*, **2018**, 65, 473-477	1.7	0
144	Epidermis Microstructure Inspired Graphene Pressure Sensor with Random Distributed Spinosum for High Sensitivity and Large Linearity. *ACS Nano*, **2018**, 12, 2346-2354	16.7	361
143	Simultaneously Detecting Subtle and Intensive Human Motions Based on a Silver Nanoparticles Bridged Graphene Strain Sensor. *ACS Applied Materials & Interfaces*, **2018**, 10, 3948-3954	9.5	85
142	Controlled Growth of Bilayer-MoS2 Films and MoS2-Based Field-Effect Transistor (FET) Performance Optimization. *Advanced Electronic Materials*, **2018**, 4, 1700524	6.4	13
141	Hybrid graphene/cadmium-free ZnSe/ZnS quantum dots phototransistors for UV detection. *Scientific Reports*, **2018**, 8, 5107	4.9	16
140	A Graphene-Based Filament Transistor with Sub-10 mVdec□ Subthreshold Swing. *Advanced Electronic Materials*, **2018**, 4, 1700608	6.4	12
139	Graphene FET Array Biosensor Based on ssDNA Aptamer for Ultrasensitive Hg Detection in Environmental Pollutants. *Frontiers in Chemistry*, **2018**, 6, 333	5	34
138	Multilayer Graphene Epidermal Electronic Skin. *ACS Nano*, **2018**, 12, 8839-8846	16.7	180
137	Field effect properties of single-layer MoS2(1□)Se2x nanosheets produced by a one-step CVD process. *Journal of Materials Science*, **2018**, 53, 14447-14455	4.3	3
136	Graphene Textile Strain Sensor with Negative Resistance Variation for Human Motion Detection. *ACS Nano*, **2018**, 12, 9134-9141	16.7	284

135	A Review on Bacteriorhodopsin-Based Bioelectronic Devices. *Sensors*, **2018**, 18,	3.8	27
134	Locally hydrazine doped WSe p-n junction toward high-performance photodetectors. *Nanotechnology*, **2018**, 29, 015203	3.4	22
133	A novel cell-scale bio-nanogenerator based on electron-ion interaction for fast light power conversion. *Nanoscale*, **2018**, 10, 526-532	7.7	7
132	Interface Engineering with MoS -Pd Nanoparticles Hybrid Structure for a Low Voltage Resistive Switching Memory. *Small*, **2018**, 14, 1702525	11	37
131	Heterostructured graphene quantum dot/WSe2/Si photodetector with suppressed dark current and improved detectivity. *Nano Research*, **2018**, 11, 3233-3243	10	38
130	Ultra-sensitive and plasmon-tunable graphene photodetectors for micro-spectrometry. *Nanoscale*, **2018**, 10, 20013-20019	7.7	25
129	Ink-injected dual-band antennas based on graphene flakes, carbon nanotubes and silver nanowires.. *RSC Advances*, **2018**, 8, 37534-37539	3.7	3
128	High Performance 2D Perovskite/Graphene Optical Synapses as Artificial Eyes **2018**,		13
127	First Principles Study of Memory Selectors using Heterojunctions of 2D Layered Materials **2018**,		2
126	Multifunctional Mechanical Sensors for Versatile Physiological Signal Detection. *ACS Applied Materials & Interfaces*, **2018**, 10, 44173-44182	9.5	22
125	Self-Powered MoS2–PDPP3T Heterotransistor-Based Broadband Photodetectors. *Advanced Electronic Materials*, **2018**, 5, 1800580	6.4	10
124	High-Quality Reconfigurable Black Phosphorus p-n Junctions. *IEEE Transactions on Electron Devices*, **2018**, 1-5	2.9	3
123	Toward an In Situ Phosphate Sensor in Natural Waters Using a Microfluidic Flow Loop Analyzer. *Journal of the Electrochemical Society*, **2018**, 165, B737-B745	3.9	8
122	Gait Recognition Based on Graphene Porous Network Structure Pressure Sensors for Rehabilitation Therapy **2018**,		4
121	Millimeter-Scale Nonlocal Photo-Sensing Based on Single-Crystal Perovskite Photodetector. *IScience*, **2018**, 7, 110-119	6.1	8
120	Direct laser-patterned ultra-wideband antennae with carbon nanotubes.. *RSC Advances*, **2018**, 8, 31331-31336		3
119	Wearable humidity sensor based on porous graphene network for respiration monitoring. *Biosensors and Bioelectronics*, **2018**, 116, 123-129	11.8	172
118	An ultrasensitive strain sensor with a wide strain range based on graphene armour scales. *Nanoscale*, **2018**, 10, 11524-11530	7.7	57

117	MoS2 Synaptic Transistor With Tunable Weight Profile. *IEEE Transactions on Electron Devices*, **2018**, 65, 3543-3547	2.9	8
116	An intelligent artificial throat with sound-sensing ability based on laser induced graphene. *Nature Communications*, **2017**, 8, 14579	17.4	275
115	Simulation and experimental verification of silicon dioxide deposition by PECVD. *Modern Physics Letters B*, **2017**, 31, 1750055	1.6	0
114	High-performance sound source devices based on graphene woven fabrics. *Applied Physics Letters*, **2017**, 110, 093110	3.4	9
113	Low-Voltage Unipolar Inverter Based on Top-Gate Electric-Double-Layer Thin-Film Transistors Gated by Silica Proton Conductor. *IEEE Electron Device Letters*, **2017**, 38, 875-878	4.4	6
112	Novel Field Effect Transistor Fabrication Based on Non-Graphene 2D Materials. *MRS Advances*, **2017**, 2, 3675-3684	0.7	
111	High-performance graphene-based flexible heater for wearable applications. *RSC Advances*, **2017**, 7, 27001-27006	3.7	66
110	Self-adapted and tunable graphene strain sensors for detecting both subtle and large human motions. *Nanoscale*, **2017**, 9, 8266-8273	7.7	76
109	Top-Gate Electric-Double-Layer IZO-Based Synaptic Transistors for Neuron Networks. *IEEE Electron Device Letters*, **2017**, 38, 588-591	4.4	24
108	Long-Term Depression Mimicked in an IGZO-Based Synaptic Transistor. *IEEE Electron Device Letters*, **2017**, 38, 191-194	4.4	39
107	Flexible graphene sound device based on laser reduced graphene. *Applied Physics Letters*, **2017**, 111, 103104	3.4	18
106	Synaptic Computation Demonstrated in a Two-Synapse Network Based on Top-Gate Electric-Double-Layer Synaptic Transistors. *IEEE Electron Device Letters*, **2017**, 38, 1496-1499	4.4	13
105	Efficient and Reversible Electron Doping of Semiconductor-Enriched Single-Walled Carbon Nanotubes by Using Decamethylcobaltocene. *Scientific Reports*, **2017**, 7, 6751	4.9	29
104	A Ferroelectric Thin Film Transistor Based on Annealing-Free HfZrO Film. *IEEE Journal of the Electron Devices Society*, **2017**, 5, 378-383	2.3	26
103	Large-Scale and High-Density pMUT Array Based on Isolated Sol-Gel PZT Membranes for Fingerprint Imaging. *Journal of the Electrochemical Society*, **2017**, 164, B377-B381	3.9	10
102	Graphene-Paper Pressure Sensor for Detecting Human Motions. *ACS Nano*, **2017**, 11, 8790-8795	16.7	381
101	Extremely Low Operating Current Resistive Memory Based on Exfoliated 2D Perovskite Single Crystals for Neuromorphic Computing. *ACS Nano*, **2017**, 11, 12247-12256	16.7	201
100	Tailoring perpendicular magnetic anisotropy with graphene oxide membranes. *RSC Advances*, **2017**, 7, 52938-52944	3.7	1

99	A super flexible and custom-shaped graphene heater. *Nanoscale*, **2017**, 9, 14357-14363	7.7	44
98	A power manager system with 78% efficiency for high-voltage triboelectric nanogenerators. *Science China Information Sciences*, **2017**, 60, 1	3.4	
97	Surface Acoustic Wave Devices Based on High Quality Temperature-Compensated Substrates. *IEEE Electron Device Letters*, **2016**, 37, 1063-1066	4.4	5
96	Tunable graphene oxide reduction and graphene patterning at room temperature on arbitrary substrates. *Carbon*, **2016**, 109, 173-181	10.4	23
95	High performance flexible strain sensor based on self-locked overlapping graphene sheets. *Nanoscale*, **2016**, 8, 20090-20095	7.7	87
94	Carbonized Silk Fabric for Ultrastretchable, Highly Sensitive, and Wearable Strain Sensors. *Advanced Materials*, **2016**, 28, 6640-8	24	584
93	A point acoustic device based on aluminum nanowires. *Nanoscale*, **2016**, 8, 5516-25	7.7	11
92	A miniaturized microbial fuel cell with three-dimensional graphene macroporous scaffold anode demonstrating a record power density of over 10,000 W m(-3) . *Nanoscale*, **2016**, 8, 3539-47	7.7	71
91	A Flexible 360-Degree Thermal Sound Source Based on Laser Induced Graphene. *Nanomaterials*, **2016**, 6,	5.4	15
90	A comparison of Pd and Au electrodes-based LiNbO3 surface acoustic wave devices. *Modern Physics Letters B*, **2016**, 30, 1650349	1.6	2
89	A Low Input Current and Wide Conversion Ratio Buck Regulator with 75% Efficiency for High-Voltage Triboelectric Nanogenerators. *Scientific Reports*, **2016**, 6, 19246	4.9	14
88	High performance photodetector based on Pd-single layer MoS2 Schottky junction. *Applied Physics Letters*, **2016**, 109, 201904	3.4	13
87	A novel thermal acoustic device based on porous graphene. *AIP Advances*, **2016**, 6, 015105	1.5	9
86	Flexible, Highly Sensitive, and Wearable Pressure and Strain Sensors with Graphene Porous Network Structure. *ACS Applied Materials & Interfaces*, **2016**, 8, 26458-26462	9.5	285
85	Wearable Strain Sensors: Carbonized Silk Fabric for Ultrastretchable, Highly Sensitive, and Wearable Strain Sensors (Adv. Mater. 31/2016). *Advanced Materials*, **2016**, 28, 6639	24	11
84	Observation of a giant two-dimensional band-piezoelectric effect on biaxial-strained graphene. *NPG Asia Materials*, **2015**, 7, e154-e154	10.3	46
83	A graphene-based resistive pressure sensor with record-high sensitivity in a wide pressure range. *Scientific Reports*, **2015**, 5, 8603	4.9	329
82	Coherent Generation of Photo-Thermo-Acoustic Wave from Graphene Sheets. *Scientific Reports*, **2015**, 5, 10582	4.9	23

81	A spectrally tunable all-graphene-based flexible field-effect light-emitting device. *Nature Communications*, **2015**, 6, 7767	17.4	97
80	A pressure sensing system for heart rate monitoring with polymer-based pressure sensors and an anti-interference post processing circuit. *Sensors*, **2015**, 15, 3224-35	3.8	57
79	Controllable thermal rectification realized in binary phase change composites. *Scientific Reports*, **2015**, 5, 8884	4.9	43
78	Graphene Dynamic Synapse with Modulatable Plasticity. *Nano Letters*, **2015**, 15, 8013-9	11.5	180
77	A high performance triboelectric nanogenerator for self-powered non-volatile ferroelectric transistor memory. *Nanoscale*, **2015**, 7, 17306-11	7.7	36
76	Zno field-effect transistors with lead-zirconate-titanate ferroelectric gate. *Materials Research Innovations*, **2015**, 19, S2-181-S2-184	1.9	2
75	Memory Devices: In Situ Tuning of Switching Window in a Gate-Controlled Bilayer Graphene-Electrode Resistive Memory Device (Adv. Mater. 47/2015). *Advanced Materials*, **2015**, 27, 7766-7766	24	1
74	Flexible CNT-array double helices Strain Sensor with high stretchability for Motion Capture. *Scientific Reports*, **2015**, 5, 15554	4.9	43
73	In Situ Tuning of Switching Window in a Gate-Controlled Bilayer Graphene-Electrode Resistive Memory Device. *Advanced Materials*, **2015**, 27, 7767-74	24	40
72	A flexible, transparent and ultrathin single-layer graphene earphone. *RSC Advances*, **2015**, 5, 17366-17371	3.7	31
71	Wafer-scale integration of graphene-based electronic, optoelectronic and electroacoustic devices. *Scientific Reports*, **2014**, 4, 3598	4.9	84
70	Novel field-effect Schottky barrier transistors based on graphene-MoS2 heterojunctions. *Scientific Reports*, **2014**, 4, 5951	4.9	115
69	A micro-scale microbial supercapacitor **2014**,		1
68	Graphene earphones: entertainment for both humans and animals. *ACS Nano*, **2014**, 8, 5883-90	16.7	85
67	Scalable fabrication of high-performance and flexible graphene strain sensors. *Nanoscale*, **2014**, 6, 699-705	7.7	287
66	Growth and Raman spectra of single-crystal trilayer graphene with different stacking orientations. *ACS Nano*, **2014**, 8, 10766-73	16.7	39
65	Cost-effective, transfer-free, flexible resistive random access memory using laser-scribed reduced graphene oxide patterning technology. *Nano Letters*, **2014**, 14, 3214-9	11.5	93
64	PROTON IRRADIATION INFLUENCE ON THE MAGNETIC PROPERTIES OF GMR-SVs. *Modern Physics Letters B*, **2014**, 28, 1450022	1.6	2

63	REACTION SIMULATION AND EXPERIMENT OF A Cl2/Ar INDUCTIVELY COUPLED PLASMA FOR ETCHING OF SILICON. *Surface Review and Letters*, **2014**, 21, 1450038	1.1	2
62	Large-scale fabrication of graphene-based electronic and MEMS devices **2014**,		1
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